The RF Line 450 MHz CATV Amplifier

. . . designed specifically for 450 MHz CATV applications. Features ion–implanted arsenic emitter transistors with 7.0 GHz fT and an all gold metallization system.

- Specified for 53- and 60-Channel Performance
- Broadband Power Gain @ f = 40-450 MHz Gp = 34.5 dB Typ @ 50 MHz

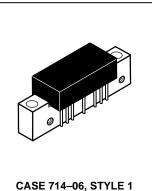
35.5 dB Typ @ 450 MHz

- Broadband Noise Figure NF = 5.0 dB (Typ)
- Superior Gain, Return Loss and DC Current Stability with Temperature
- All Gold Metallization
- 7.0 GHz Ion-Implanted Transistors



450 MHz 60-CHANNEL CATV LINE EXTENDER AMPLIFIER

MHW5342A



ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V _{in}	+55	dBmV
DC Supply Voltage	VCC	+28	Vdc
Operating Case Temperature Range	тс	-20 to +100	°C
Storage Temperature Range	T _{stg}	-40 to +100	°C

ELECTRICAL CHARACTERISTICS (V_{CC} = 24 Vdc, T_C = +30°C, 75 Ω system unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	—	450	MHz
Power Gain — 50 MHz		Gp	33.5	34.5	35.5	dB
Power Gain — 450 MHz		Gp	34.5	35.5	37	dB
Slope		S	0	+1.0	+2.5	dB
Gain Flatness (Peak To Valley)		—	—	0.3	0.6	dB
Return Loss — Input/Output (Z ₀ = 75 Ohms)	40-450 MHz	IRL/ORL	18	—	_	dB
Second Order Intermodulation Distortion (V _{out} = +46 dBmV per ch., Ch 2, M6, M15) (V _{out} = +46 dBmV per ch., Ch 2, M13, M22)		IMD		-78 -74	 -68	dB
	-Channel FLAT -Channel FLAT	XMD ₅₃ XMD ₆₀	—	-63 -63	 _59	dB
1 1	-Channel FLAT -Channel FLAT	СТВ ₅₃ СТВ ₆₀	_	-63 -62	 _59	dB
DIN (European Applications Only) 300 MHz — (CH V + Q – P @ W) 400 MHz — (CH M8 + M15 – M9 @ M14) 450 MHz — (CH M20 + M23 – M22 @ M21)		DIN1 DIN2 DIN3		126 125 124	 	dBμV
Noise Figure (f = 450 MHz)		NF	—	5.0	6.0	dB
DC Current		IDC	_	310	340	mA

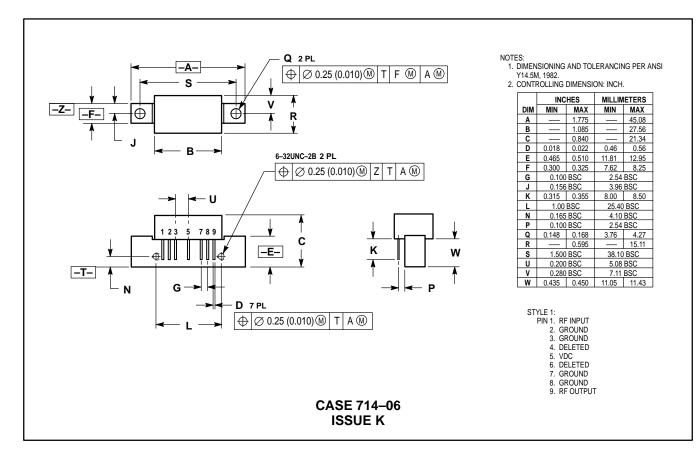


*DIN (European Applications Only)

NCTA Channel	Frequency	DIN Output Level	DIN Beat Level	
Designation	(MHz)	(dBmV)**(Typ)	dB Relative to Ref. Ch.	
P	253.25	+ 60	≤-60	
Q	259.25	+ 60		
V	289.25	+ 66		
W (Ref.)	295.25	+ 66		
M8	361.25	+ 59	≤-60	
M9	367.25	+ 59		
M14 (Ref.)	397.25	+ 65		
M15	403.25	+ 65		
M20	433.25	+ 64	≼−60	
M21 (Ref.)	439.25	+ 64		
M22	445.25	+ 58		
M23	451.25	+ 58		

**DIN (dBµV) = Reference Channel Level (dBmV) +60 dB

PACKAGE DIMENSIONS



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